

19 April 2023

Product data sheet

1. General description

The GAN190-650FBE is a general purpose 650 V, 190 m Ω Gallium Nitride (GaN) FET in a DFN 5 mm x 6 mm surface mount package. It is a normally-off e-mode device offering superior performance.

2. Features and benefits

- · Enhancement mode normally-off power switch
- · Ultra high frequency switching capability
- · No body diode
- · Low gate charge, low output charge
- Qualified for standard applications
- ESD protection
- · RoHS, Pb-free, REACH-compliant
- High efficiency and high power density
- Low package inductance and low package resistance

3. Applications

- · High power density and high efficiency power conversion
- · AC-to-DC converters, totem pole PFC
- DC-to-DC converters
- Fast battery charging, mobile phone, laptop, tablet and USB type-C chargers
- Datacom and telecom (AC-to-DC and DC-to-DC) converters
- Motor drives
- · Solar (PV) inverters
- · Class D audio amplifiers, TV PSU and LED drivers

4. Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
V_{DS}	drain-source voltage	-55 °C ≤ T _j ≤ 150 °C		-	-	650	V
V _{TDS}	transient drain to source voltage	pulsed; $t_p = 1 \mu s$; $\delta_{factor} = 0.01$		-	-	800	V
I _D	drain current	V _{GS} = 6 V; T _{mb} = 25 °C	[1]	-	-	11.5	Α
P _{tot}	total power dissipation	T _{mb} = 25 °C; <u>Fig. 1</u>		-	-	125	W
Tj	junction temperature			-55	-	150	°C
Static chara	acteristics				'		'
R _{DSon}	drain-source on-state resistance	V _{GS} = 6 V; I _D = 3.9 A; T _j = 25 °C; Fig. 11; Fig. 12; Fig. 13		-	138	190	mΩ
		V _{GS} = 6 V; I _D = 3.9 A; T _j = 150 °C; Fig. 11; Fig. 14		-	300	-	mΩ



Symbol	Parameter	Conditions		Min	Тур	Max	Unit	
R _G	gate resistance	f = 5 MHz; T _j = 25 °C; open drain		-	5	-	Ω	
Dynamic characteristics								
Q_{GD}	gate-drain charge	$I_D = 3.9 \text{ A}; V_{DS} = 400 \text{ V}; V_{GS} = 6 \text{ V};$		-	1.1	-	nC	
Q _{G(tot)}	total gate charge	T _j = 25 °C; <u>Fig. 15</u> ; <u>Fig. 16</u>		-	2.8	-	nC	
Q _{oss}	output charge	$V_{GS} = 0 \text{ V}; V_{DS} = 400 \text{ V}; T_j = 25 \text{ °C}$	[2]	-	24.5	-	nC	

^[1] Limited by device saturation

5. Pinning information

Table 2. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	D	drain	4 3 2 1	
2	D	drain		
3	D	drain		D
4	D	drain		
5	S	source		$G \longrightarrow \begin{pmatrix} \vdash \\ \downarrow \\ \downarrow \end{pmatrix}$
6	S	source		KS F
7	KS	kelvin source		S aaa-036395
8	G	gate	5 6 7 8 Transparent top view	
mb	S	mounting base; connected to source	DFN5060-5 (SOT8075-1)	

6. Ordering information

Table 3. Ordering information

Type number	Package					
	Name	Description	Version			
GAN190-650FBE		plastic thermal enhanced small outline package; no leads; 5 terminals; body: 5 × 6 × 0.9 mm	SOT8075-1			

7. Marking

Table 4. Marking codes

Type number	Marking code
GAN190-650FBE	190IFBE

8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Tj = 25 °C unless otherwise stated.

Symbol	Parameter	Conditions	Min	Max	Unit
V_{DS}	drain-source voltage	-55 °C ≤ T _j ≤ 150 °C	-	650	V

^[2] Q_r is not specified separately from Q_{oss} for e-mode GaN FETs, since Q_r = Q_{oss} + Q_D, and Q_D = 0. (Q_D is charge associated with diffusion of minority carriers. Since there is no body diode, no minority carriers in excess of Q_{oss} have to be transferred for e-mode GaN FETs.)

Symbol	Parameter	Conditions		Min	Max	Unit
V_{TDS}	transient drain to source voltage	pulsed; $t_p = 1 \mu s$; $\delta_{factor} = 0.01$		-	800	V
V _{GS}	gate-source voltage			-1.4	7	V
P _{tot}	total power dissipation	T _{mb} = 25 °C; <u>Fig. 1</u>		-	125	W
I _D	drain current	V _{GS} = 6 V; T _{mb} = 25 °C	[1]	-	11.5	Α
I _{DM}	peak drain current	pulsed; $t_p \le 10 \mu s$; $T_{mb} = 25 °C$; Fig. 2	[1]	-	20.5	А
T _{stg}	storage temperature			-55	150	°C
Tj	junction temperature			-55	150	°C
T _{sld(M)}	peak soldering temperature			-	260	°C

[1] Limited by device saturation

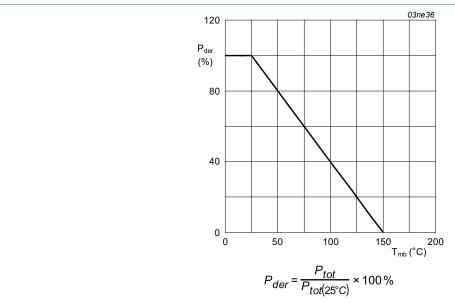
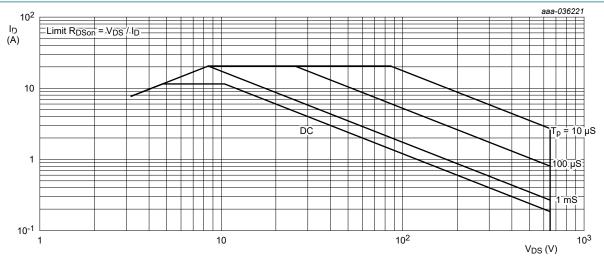


Fig. 1. Normalized total power dissipation as a function of mounting base temperature



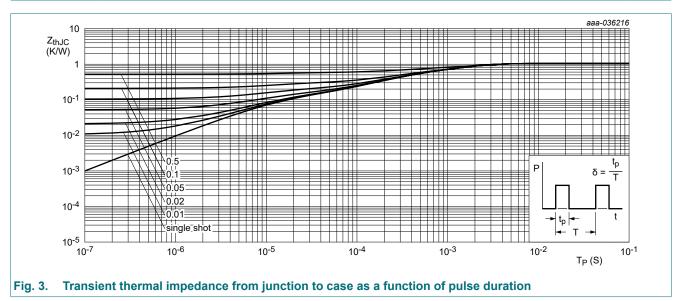
 T_{mb} = 25 °C; I_{DM} is a single pulse

Fig. 2. Safe operating area; continuous and peak drain currents as a function of drain-source voltage

9. Thermal characteristics

Table 6. Thermal characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
R _{th(j-c)}	thermal resistance from junction to case	Fig. 3	-	-	1	K/W
$R_{th(j-a)}$	thermal resistance from junction to ambient		-	-	35.9	K/W



10. Characteristics

Table 7. Characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static chara	acteristics					
V _{GS(th)}	gate-source threshold voltage	I_D = 12.2 mA; V_{DS} = V_{GS} ; T_j = 25 °C; Fig. 8	1.2	1.7	2.5	V
		I_D = 12.2 mA; V_{DS} = V_{GS} ; T_j = 150 °C; Fig. 8	-	1.7	-	V
I _{DSS}	drain leakage current	V_{DS} = 650 V; V_{GS} = 0 V; T_j = 25 °C; Fig. 9	-	0.45	20	μΑ
		V_{DS} = 650 V; V_{GS} = 0 V; T_j = 150 °C; Fig. 9	-	6	-	μΑ
I _{GSS}	gate leakage current	$V_{GS} = 6 \text{ V}; V_{DS} = 0 \text{ V}; T_j = 25 \text{ °C};$ Fig. 10	-	60	-	μΑ
R _{DSon}	drain-source on-state resistance	V _{GS} = 6 V; I _D = 3.9 A; T _j = 25 °C; Fig. 11; Fig. 12; Fig. 13	-	138	190	mΩ
		V_{GS} = 6 V; I_{D} = 3.9 A; T_{j} = 150 °C; Fig. 11; Fig. 14	-	300	-	mΩ
R _G	gate resistance	f = 5 MHz; T _j = 25 °C; open drain	-	5	-	Ω
Dynamic ch	naracteristics					
Q _{G(tot)}	total gate charge	I _D = 3.9 A; V _{DS} = 400 V; V _{GS} = 6 V;	-	2.8	-	nC
Q _{GS}	gate-source charge	T _j = 25 °C; <u>Fig. 15</u> ; <u>Fig. 16</u>	-	0.25	-	nC
Q _{GD}	gate-drain charge		-	1.1	-	nC

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
V _{GS(pl)}	gate-source plateau voltage	$I_D = 3.9 \text{ A}; V_{DS} = 400 \text{ V}; T_j = 25 ^{\circ}\text{C};$ Fig. 15		-	2.2	-	V
C _{iss}	input capacitance	V _{DS} = 400 V; V _{GS} = 0 V; f = 100 kHz;		-	96	-	pF
C _{oss}	output capacitance	T _j = 25 °C; <u>Fig. 17</u>		-	30	-	pF
C _{rss}	reverse transfer capacitance			-	0.5	-	pF
C _{o(er)}	effective output capacitance, energy related	$0 \text{ V} \le \text{ V}_{DS} \le 400 \text{ V}; \text{ V}_{GS} = 0 \text{ V};$ $\text{T}_{j} = 25 \text{ °C}; \frac{\text{Fig. } 18}{\text{ Fig. } 18}$	[1]	-	43	-	pF
C _{o(tr)}	effective output capacitance, time related	$0 \text{ V} \le \text{ V}_{DS} \le 400 \text{ V}; \text{ V}_{GS} = 0 \text{ V};$ $\text{T}_{j} = 25 \text{ °C}$	[2]	-	60	-	pF
t _{d(on)}	turn-on delay time	$V_{DS} = 400 \text{ V}; V_{GS} = 6 \text{ V}; T_j = 25 \text{ °C}; I_D =$		-	1.4	-	ns
t _r	rise time	8 A; L = 318 μH; R _{on} = $10^{\circ}\Omega$; R _{off} = $2^{\circ}\Omega$; Fig. 19; Fig. 20		-	4	-	ns
t _{d(off)}	turn-off delay time	<u> </u>		-	1.7	-	ns
t _f	fall time			-	4	-	ns
Q _{oss}	output charge	V _{GS} = 0 V; V _{DS} = 400 V; T _j = 25 °C	[3]	-	24.5	-	nC
Source-dra	in characteristics	,		'	1	1	,
V_{SD}	source-drain voltage	I _S = 3.9 A; V _{GS} = 0 V; T _j = 25 °C; Fig. 21; Fig. 22; Fig. 23; Fig. 24		-	2.6	-	V

- $C_{O(er)}$ is the fixed capacitance that gives the same stored energy as C_{OSS} while V_{DS} is rising from 0 to 400 V
- $C_{O(tr)}$ is the fixed capacitance that gives the same charging time as C_{OSS} while V_{DS} is rising from 0 to 400 V Q_r is not specified separately from Q_{oss} for e-mode GaN FETs, since $Q_r = Q_{oss} + Q_D$, and $Q_D = 0$. (Q_D is charge associated with diffusion of minority carriers. Since there is no body diode, no minority carriers in excess of Qoss have to be transferred for e-mode GaN FETs.)

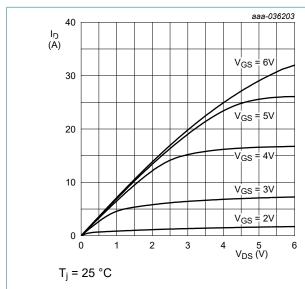


Fig. 4. Output characteristics: drain current as a function of drain-source voltage; typical values

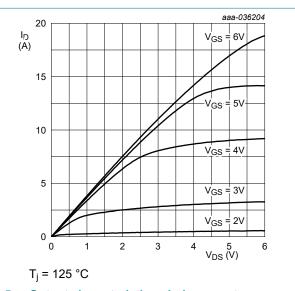


Fig. 5. Output characteristics: drain current as a function of drain-source voltage; typical values

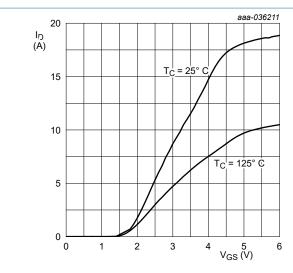
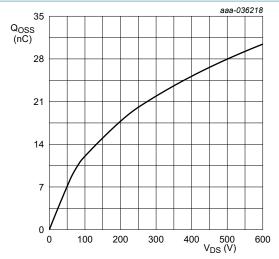


Fig. 6. Transfer characteristics; drain current as a function of gate-source voltage; typical values



Freq. = 100 kHz

Fig. 7. Output charge as a function of drain-source voltage; typical values

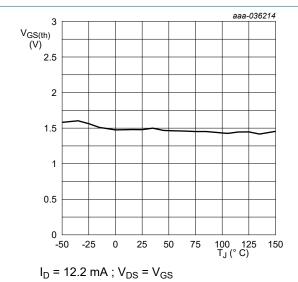


Fig. 8. Gate-source threshold voltage as a function of junction temperature

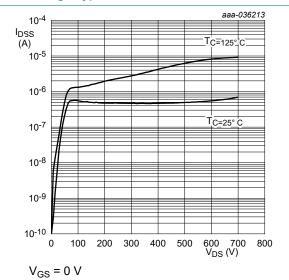


Fig. 9. Drain-source current as a function of drainsource voltage; typical values

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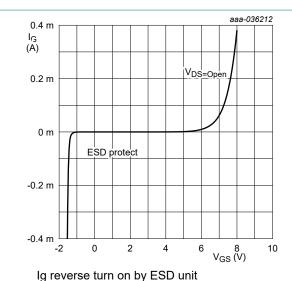


Fig. 10. Gate-source current as a function of gatesource voltage; typical values

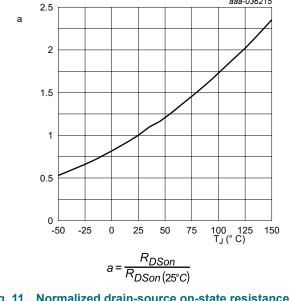


Fig. 11. Normalized drain-source on-state resistance factor as a function of junction temperature

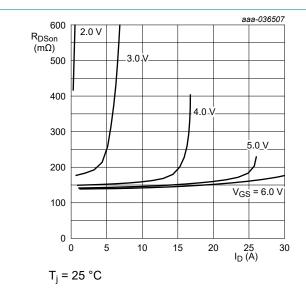


Fig. 12. Drain-source on-state resistance as a function of drain current; typical values

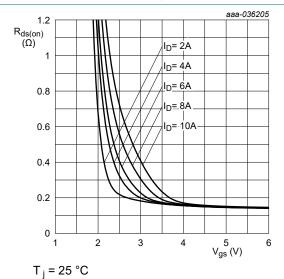


Fig. 13. Drain-source on-state resistance as a function of gate-source voltage; typical values

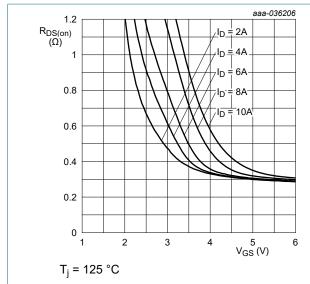


Fig. 14. Drain-source on-state resistance as a function of gate-source voltage; typical values

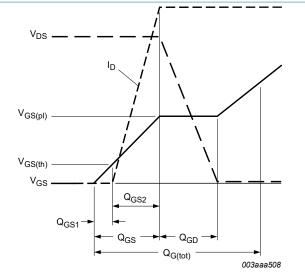


Fig. 15. Gate charge waveform definitions

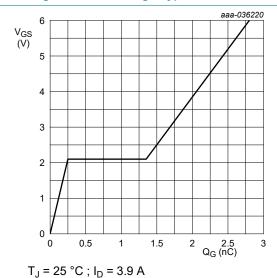


Fig. 16. Gate-source voltage as a function of gate charge; typical values

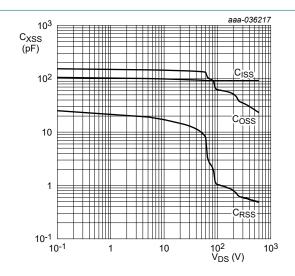


Fig. 17. Input, output and reverse transfer capacitances as a function of drain-source voltage; typical values

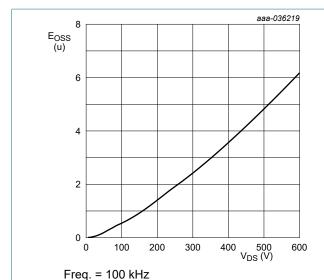


Fig. 18. COSS stored energy as a function of drainsource voltage; typical values

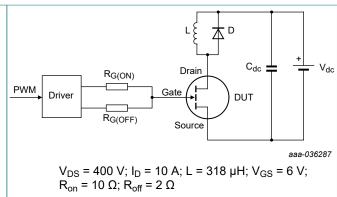


Fig. 19. Typical switching times with inductive load

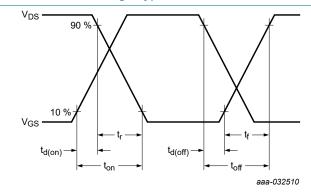


Fig. 20. Switching time waveform

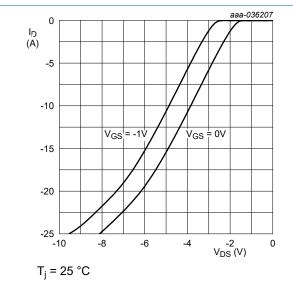


Fig. 21. Source current as a function of source-drain voltage; typical values

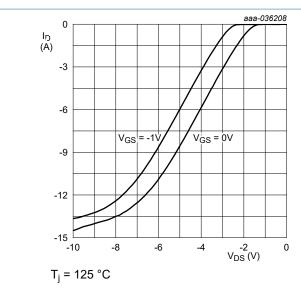


Fig. 22. Source current as a function of source-drain voltage; typical values

T_i = 125 °C

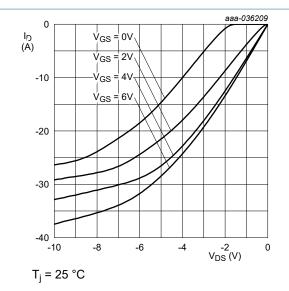


Fig. 23. Source current as a function of source-drain voltage; typical values

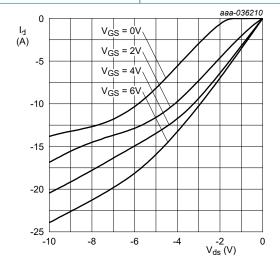


Fig. 24. Source current as a function of source-drain voltage; typical values

11. Package outline

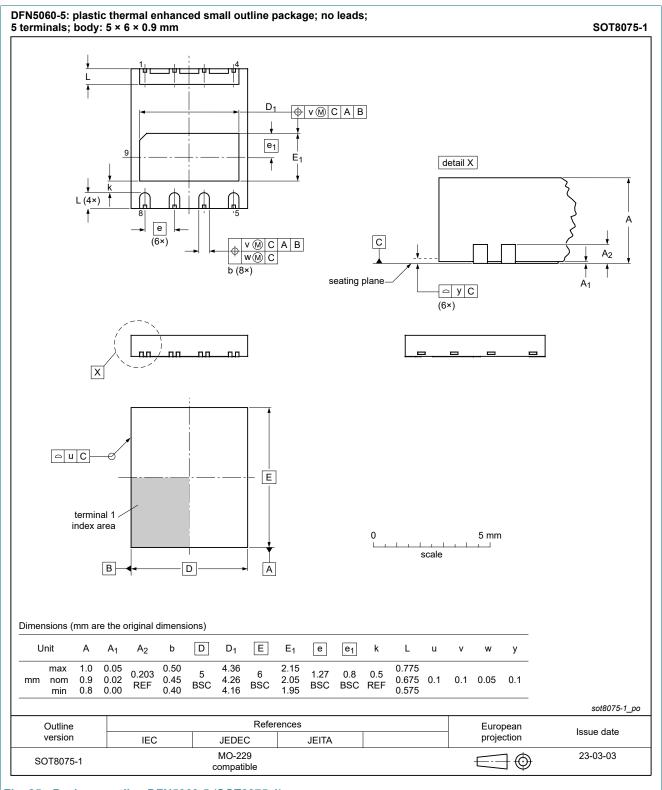
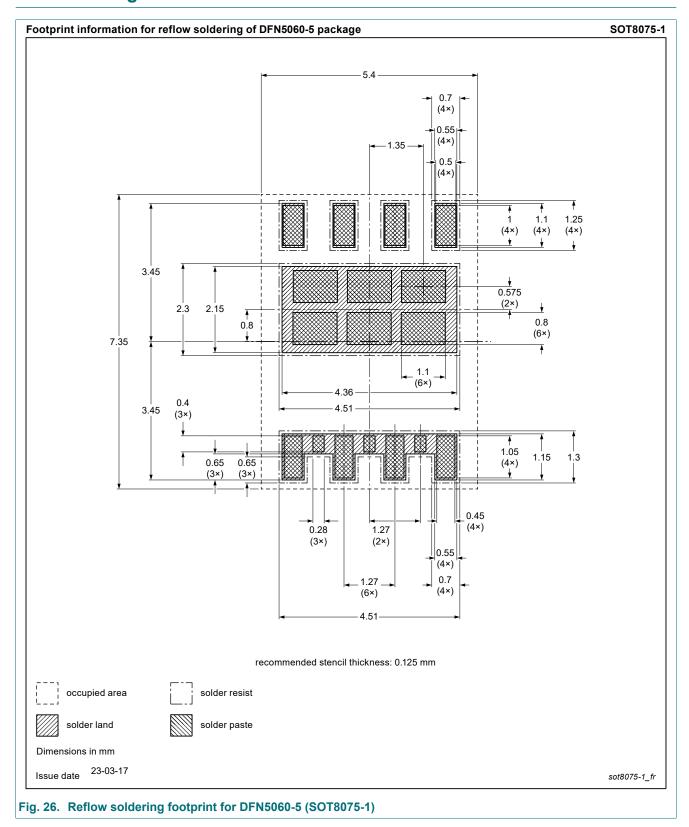


Fig. 25. Package outline DFN5060-5 (SOT8075-1)

12. Soldering



13. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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Contents

1.	General description	1
	Features and benefits	
3.	Applications	1
4.	Quick reference data	1
5.	Pinning information	2
6.	Ordering information	2
7.	Marking	2
	Limiting values	
	Thermal characteristics	
10.	. Characteristics	4
	Package outline	
	. Soldering	
	Legal information	

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